# LM(2)5119 Wide VIN Range Dual Synchronous Buck Controller

Note: The components calculated here are reasonable starting values for a design using the LM(2)5119 wide VIN controller. As such, components are not optimized for any particular performance attribute. Only one channel is shown. Calculate each channel separately for dual-output designs. Each channel is identical for interleaved designs.

Enter design parameters in the shaded cells

**Step 7: Ramp Configuration** 

Version 1.5 1/27/2014

 $R_{RAMP}$  [k $\Omega$ ]

73.2

in the shaded cone		
Step 1: General Requirements	V <sub>IN</sub> (min) [V]	14
•	V <sub>IN</sub> (max) [V]	55
	V <sub>OUT</sub> [V]	5
	Max Load Current per Channel [A]	8
	Ripple Current as % of Max Load Current	15%
	Minimum Duty Cycle	0.09
	Maximum Duty Cycle	0.36
Step 2: Interleaved or Dual O/P	Interleaved / Dual Output Operation	Dual Outpu
	IC Package	WQFN-32
	Recommended IC	LM5119
Stan 3: Switching Fraguency	F <sub>sw</sub> [kHz]	230

Step 3: Switching Frequency	rsw [Ki iz]	230
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Step 4: Frequency Programming	Recommneded $R_T$ [k $\Omega$ ]	21.7
Step 5: Filter Inductance	Recommended L <sub>F</sub> per channel [µH]	16.5
	Enter L <sub>F</sub> [µH]	15
	Max Inductor Ripple Current [A]	1.3
Step 6: Current Limit	Target (% beyond Max Load)	20%

	3 - ( )	
	9.6	
	a. a	
	Slope Compensation Factor (K)	2.5
	Recommended $R_S$ [m $\Omega$ ] per Channel	9.4
	Enter Closest Standard Value for $R_S$ [m $\Omega$ ]	10
	Peak Output Current with Output Short [A]	12.4

	Recommneded $C_{RAMP}$ [pF]	820
	-	
Step 8: Output Capacitors	C <sub>OUT1</sub> per channel [µF]	470
	C <sub>OUT2</sub> per channel [µF]	20
	Net Output Cap ESR per channel [mΩ]	13
	С <sub>ОUТ1</sub> + С <sub>ОUТ2</sub> [µF]	490
	Peak-peak VOUT Ripple [mV]	17.2

Step 9: Input Capacitors	Input Capacitor C <sub>IN</sub> [μF]	17.6
	Input Voltage Ripple [V)]	0.49

Step 10: VIN UV Shutdown	UV Shutdown Voltage [V]	13
	UV Hysteresis, V <sub>HYS</sub> [V]	1.25
	Upper UVLO Resistor $R_{UV2}$ [k $\Omega$ ]	62.5
	Lower UVLO Resistor R <sub>UV1</sub> [kΩ]	6.65

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Step 11: Feedback Resistors	Lower FB Resistor R <sub>FB1</sub> [kΩ]	1.33
	Upper FB Resistor Report KO1	6.98

Step 11: Feedback Resistors	FOMELL D LEGISIOL LEBI [KZZ]	1.33
	Upper FB Resistor R <sub>FB2</sub> [kΩ]	6.98
Step 12: Compensation Network	Loop Bandwidth [kHz]	11
	Recommended $R_{COMP}$ [k $\Omega$ ]	27.4
	$R_{COMP}[k\Omega]$	36.5
	Recommneded C <sub>COMP</sub> [nF]	6.3
	C <sub>COMP</sub> [nF]	6.8
	Recommended Max C <sub>HF</sub> [pF]	179
	Recommended Min C <sub>HF</sub> [pF]	17
	C <sub>HF</sub> [pF]	100
Step 13: Soft-Start Capacitor	Soft-Start Time [ms]	3.8
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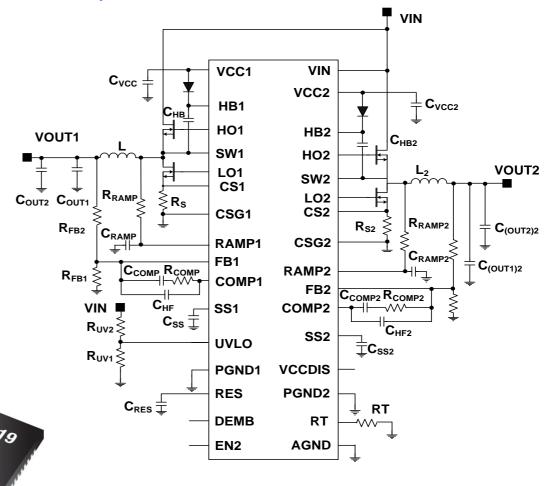
Step 13: Soft-Start Capacitor	Soft-Start Time [ms]	3.8
	Soft-Start Capacitor C <sub>SS</sub> [nF]	48
Step 14: MOSFET Gate Charge	High-side MOSFET Qg @ V <sub>VCC</sub> [nC]	30

Low-side MOSFET Qg @  $V_{VCC}$  [nC]

	MOSFET Total Gate Charge [nC]	60
	_	
Step 15: Boot & VCC Capacitors	Minimum C <sub>VCC</sub> [μF]	0.40
	Minimum С <sub>нв</sub> [µF]	0.20
	VCC Run Current I <sub>VCC</sub> [mA]	18

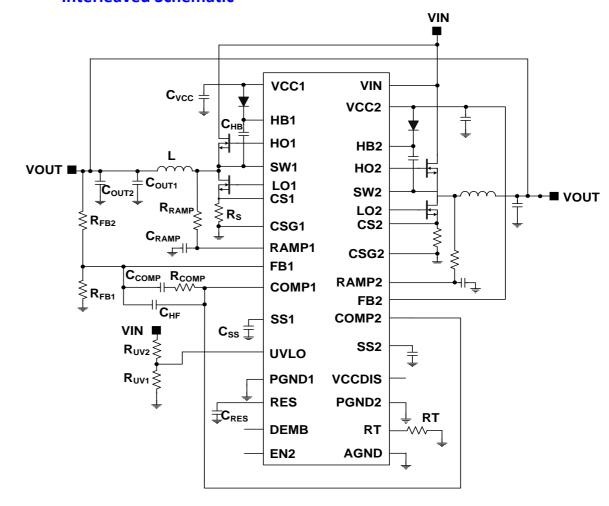
	VCC Run Current I <sub>VCC</sub> [mA]	18
Step 16: Restart Capacitor	Restart Time [ms]	59
	Restart Canacitor Cosa [uF]	0.47

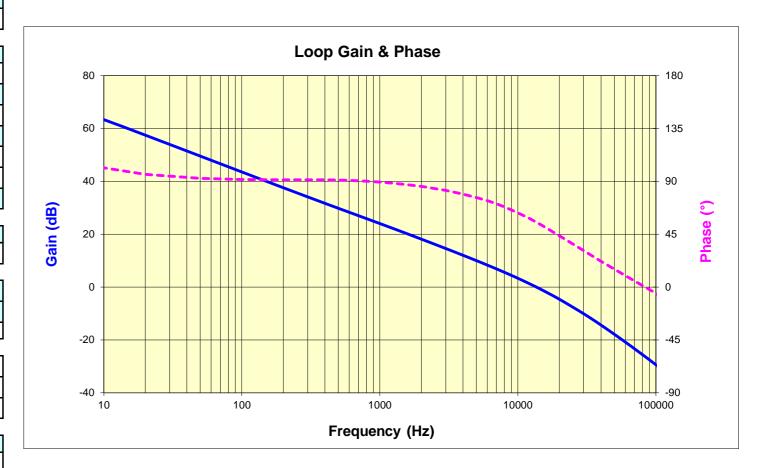
## **Dual Output Schematic**



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### **Interleaved Schematic**





### LM(2)5119 Power Dissipation Calculations



### Enter design parameters in the shaded cells

#### **Common Assumptions**

#### **Channel 2 Requirements**

Ambient Temperature T<sub>A</sub> 50°C

Package thermal Resisitance R<sub>JA</sub> 40°C/W

External VCC Select "Yes" or "No"

External VCC (V) 10

High-side MOSFET Qg @ V<sub>VCC</sub> (nC) 20

Low-side MOSFET Qg @ V<sub>VCC</sub> (nC) 46

Channel 2 Total Gate Charge (nC) 66

Channel 2 VCC Run Current I<sub>CC</sub> (mA) 17



#### **Channel 1 Thermal Calculations**

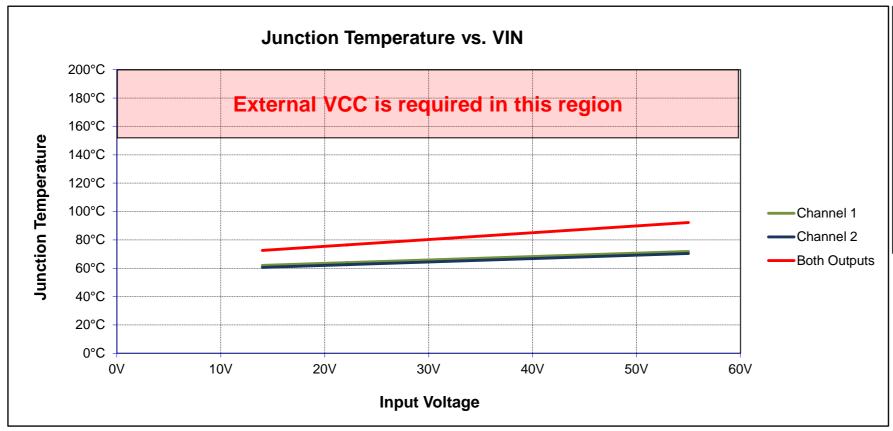
VIN	14.0V	18.1V	22.2V	22.1V	30.4V	34.5V	38.6V	42.7V	46.8V	50.9V	55.0V
IC Power	0.300W	0.325W	0.349W	0.349W	0.398W	0.423W	0.448W	0.472W	0.497W	0.521W	0.546W
$\Delta T_J$ above $T_A$	12°C	13°C	14°C	14°C	16°C	17°C	18°C	19°C	20°C	21°C	22°C
Junction Temperature	62°C	63°C	64°C	64°C	66°C	67°C	68°C	69°C	70°C	71°C	72°C

#### **Channel 2 Thermal Calculations**

VIN	14.0V	18.1V	22.2V	22.1V	30.4V	34.5V	38.6V	42.7V	46.8V	50.9V	55.0V
IC Power	0.264W	0.288W	0.313W	0.312W	0.362W	0.387W	0.411W	0.436W	0.461W	0.485W	0.510W
$\Delta T_J$ above $T_A$	11°C	12°C	13°C	12°C	14°C	15°C	16°C	17°C	18°C	19°C	20°C
Junction Temperature	61°C	62°C	63°C	62°C	64°C	65°C	66°C	67°C	68°C	69°C	70°C

#### Channel 1 + Channel 2 Thermal Calculations

Chamer 1 + Chamer 2 Thermal Calculations											
VIN	14.0V	18.1V	22.2V	22.1V	30.4V	34.5V	38.6V	42.7V	46.8V	50.9V	55.0V
Total IC Power	0.564W	0.613W	0.662W	0.661W	0.761W	0.810W	0.859W	0.908W	0.957W	1.007W	1.056W
$\Delta T_J$ above $T_A$	23°C	25°C	26°C	26°C	30°C	32°C	34°C	36°C	38°C	40°C	42°C
Junction Temperature	73°C	75°C	76°C	76°C	80°C	82°C	84°C	86°C	88°C	90°C	92°C



The graph labeled "Channel 1" is the junction temperature rise for Channel 1 operating with Channel 2 off. The "Channel 2" graph is the junction temperature for Channel 2 operating with Channel 1 off. The graph labeled "Both Outputs" gives the junction temperature with both outputs operating.

Potentially high junction temperatures at high VIN may occur when both outputs are operating. Either decrease the switching frequency, decrease VIN, select lower gate charge MOSFETs or use an external source for VCC to reduce operating junction temperature.

## LM(2)5119 Bode Plot Calculations



Frequency (Hz)	Frequency (rad/sec)	Modulator Gain (dB)	Modulator Phase (°)	Error Amplifier Gain (dB)	Error Amplifier Phase (°)	Loop Gain (dB)	Loop Phase (°)
`1	6.28E+00	13.2	-0.1	63	154	76.4	153.9
2	1.26E+01	13.2	-0.2	61	136	74.4	135.6
5	3.14E+01	13.2	-0.4	56	113	68.9	112.3
10	6.28E+01	13.2	-0.8	50	102	63.3	101.6
20	1.26E+02	13.2	-1.7	44	98	57.5	95.9
50	3.14E+02	13.2	-4.2	36	97	49.5	92.6
100	6.28E+02	13.1	-8.3	30	100	43.5	91.6
200	1.26E+03	12.9	-16.2	25	108	37.6	91.3
400	2.51E+03	12.0	-30.2	20	121	31.7	91.2
600	3.77E+03	10.8	-41.3	17	132	28.3	90.8
800	5.03E+03	9.6	-49.7	16	140	25.9	90.2
1000	6.28E+03	8.4	-56.1	16	146	24.0	89.4
1200	7.54E+03	7.2	-61.1	15	150	22.5	88.6
1500	9.42E+03	5.7	-66.6	15	154	20.6	87.5
2000	1.26E+04	3.6	-72.8	15	158	18.1	85.7
3000	1.88E+04	0.3	-79.9	14	162	14.6	82.3
4000	2.51E+04	-2.2	-84.1	14	163	12.0	79.2
5000	3.14E+04	-4.1	-86.9	14	163	10.0	76.3
6000	3.77E+04	-5.7	-89.1	14	163	8.3	73.5
7000	4.40E+04	-7.1	-90.9	14	162	6.9	70.7
8000	5.03E+04	-8.3	-92.4	14	160	5.6	68.1
9000	5.65E+04	-9.4	-93.6	14	159	4.4	65.6
10000	6.28E+04	-10.4	-94.7	14	158	3.3	63.2
12000	7.54E+04	-12.1	-96.6	14	155	1.4	58.6
15000	9.42E+04	-14.3	-98.6	13	151	-1.1	52.4
20000	1.26E+05	-17.2	-100.7	13	144	-4.6	43.7
30000	1.88E+05	-21.3	-102.7	11	134	-10.1	30.9
40000	2.51E+05	-24.1	-103.7	10	126	-14.4	21.9
60000	3.77E+05	-28.0	-105.7	7	115	-20.8	9.7
100000	6.28E+05	-32.8	-110.6	3	105	-29.4	-5.4
200000	1.26E+06	-39.5	-125.1	-2	96	-41.8	-29.3
350000	2.20E+06	-45.7	-146.3	-7	90	-52.9	-55.9
600000	3.77E+06	-53.4	-174.3	-12	85	-65.3	-89.2
1000000	6.28E+06	-62.9	157.3	-16	79	-79.4	236.3

### Frequency Compensation

Compensation
Parameters

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 $Z_{\mathsf{EA}}$ 

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Modulator				
ωp_lf	4382 rad/s	697 Hz		
ωp_hf	115000 rad/s	18.3 kHz		
ωz_esr	163666 rad/s	26.0 kHz	Additional Definitions	
ωp_esr	4009820 rad/s	638 kHz		
ωn	722566 rad/s	115 kHz	RLOAD	0.625
			DC GAIN MOI	0.006
Am	4.6 V/V	13.2 dB	VCC	7.6
Error Amplifier				
ωzero	4029 rad/s	641 Hz		
ωpole	20756 rad/s	3.3 kHz		
ωhf	278002 rad/s	44.2 kHz		
ωbw	1.9E+07 rad/s	3 MHz		

80 dB 300 Hz

3.3 kHz

-15.9 dB

10000 V/V

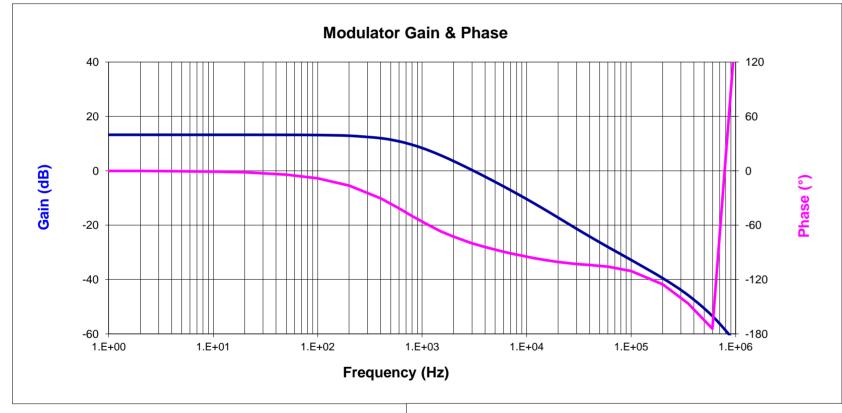
-1.57 V/V

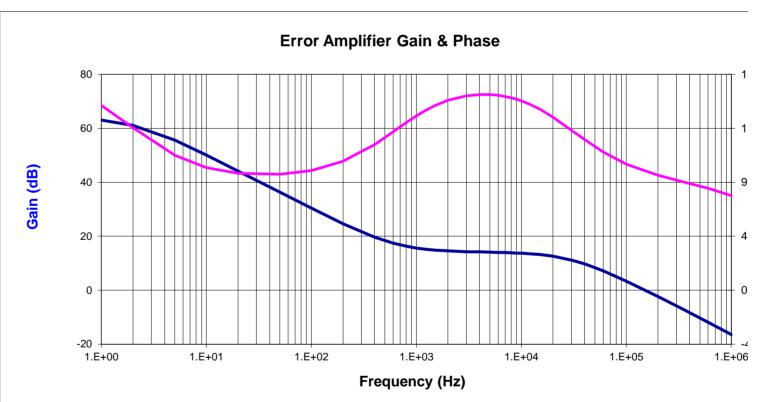
 $3303~\Omega$  20756 rad/s

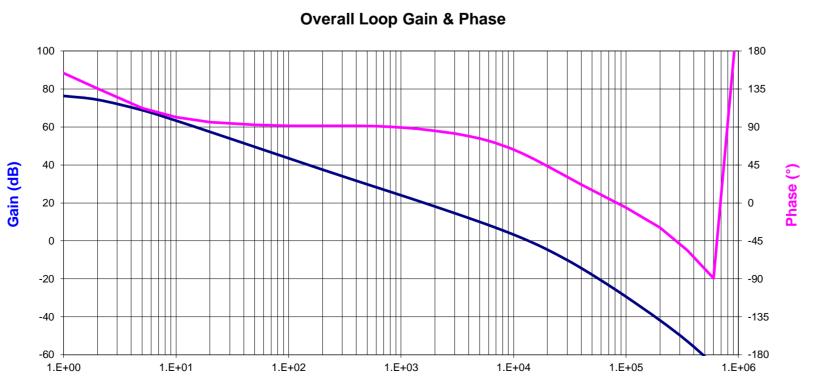
4.883 Ω 0.160 V/V

1885 rad/s

Ω V/V V







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